

# AMP00760-50 SOLID STATE HIGH POWER AMPLIFIER

## FEATURES

- Rack mount system
- Class AB linear GaN design
- Instantaneous wide bandwidth
- Suitable for all modulations standards
- Built-in protection circuits
- High reliability and ruggedness



## ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	0.7 - 6.0 GHz	
Power Output @ Psat	50 Watt Typ	CW
Power Gain	47 dB Min	
Power Gain Flatness	3.0 dB p-p	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	37dBm/Tone, $\Delta = 1\text{MHz}$
Harmonics	-20 dBc Typ	At rated output power
Non Harmonics Spurious	-60dBc Max	
Operating Voltage	100 - 240 VAC	Single phase
Power Consumption	400 Watt Max	At Rated Pout
Max Input Power	+8 dBm	Without damage
Load VSWR Protection	$\infty : 1$	
Sample Port Coupling Factor	40 dB Nom	

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensing

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 562 mm	2U, excluding handles
Weight	10 kg.	
RF Connectors In/Out	Type-N Female	
Sample Port Connector	SMA-Female	
Interface Connector	9-Pin D-Sub	See table pin assignment
AC Power Connector	IEC 60320-C14	
Cooling	Built in Fan Cooling	
<b>OPTIONAL:</b> Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, Optional GPIB Interface	Remote Bluetooth application

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## D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	Reserved	N/C
2	Reserved	N/C
3	CURRENT SENSOR	$I_p @ 50mV/100mA$ Typ
4	TEMP SENSOR	$V_T @ 10mV/^{\circ}C + 500mV$ Typ
5	SHUTDOWN	TTL - Standby Mode
6	VDD	Internal Power Supply Voltage
7	Reserved	N/C
8, 9	GND	Ground

## OUTLINE DRAWING

